## NSN 5962-01-122-4431

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-122-4431 **Body Length:** 0.960 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 794.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Ky-801b 11627 **Features Provided:** Hermetically sealed and schottky and bipolar and 3-state output and programmable and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 stage **Case Outline Source And Designator:** D-6 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Terminal Type And Quantity:** 18 printed circuit

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N/a

Shelf Life:

**Unit Of Measure:** 

## NSN 5962-01-122-4431

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

A458a0